

# isc N-Channel MOSFET Transistor

## IRFI540N

### • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(on) ≤ 52mΩ (max)
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

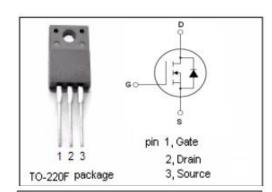
• reliable device for use in a wide variety of applications

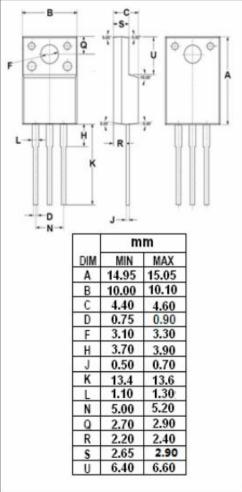
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	100	V	
V <sub>GS</sub>	Gate-Source Voltage ±20		V	
I <sub>D</sub>	Drain Current-Continuous	20	А	
I <sub>DM</sub>	Drain Current-Single Pulsed 110		А	
P <sub>D</sub>	Total Dissipation @Tc=25℃	on @T <sub>C</sub> =25℃ 54		
Tj	Max. Operating Junction Temperature 175		$^{\circ}\mathbb{C}$	
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.8	°C/W







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250uA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =11A			52	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V			25	μ <b>А</b>
V <sub>SD</sub>	Diode forward voltage	I <sub>DR</sub> =11A, V <sub>GS</sub> = 0 V			1.3	V

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